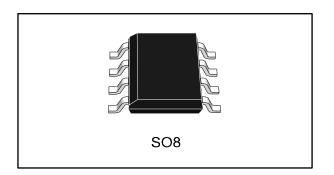


3.3 V powered, 15 kV ESD protected, up to 12 Mbps RS-485/ RS-422 transceiver

Datasheet - production data



## Features

- ESD protection
  - ±15 kV IEC 61000-4-2 air discharge
  - ±8 kV IEC 61000-4-2 contact discharge
- Operate from a single 3.3 V supply no charge pump required
- Interoperable with 5 V logic
- 1 µA low current shutdown mode max.
- Guaranteed 12 Mbps data rate
- -7 to 12 V common mode input voltage range
- Half duplex versions available
- Industry standard 75176 pinout

- Current limiting and thermal shutdown for driver overload protection
- Guaranteed high receiver output state for floating inputs with no signal present
- Allow up to 64 transceivers on the bus
- Available in SO8 package
- Automotive grade (ST3485EIY)

## Description

The ST3485EB/EC/EI/EIY device is ±15 kV ESD protected, 3.3 V low power transceiver for RS-485 and RS-422 communications. The device contains one driver and one receiver in half duplex configuration.

The ST3485E device transmits and receives at a guaranteed data rate of at least 12 Mbps.

All transmitter outputs and receiver inputs are protected to  $\pm 15$  kV IEC 61000-4-2 air discharge.

The driver is short-circuit current limited and is protected against excessive power dissipation by thermal shutdown circuitry that places the driver outputs into a high impedance state.

#### Table 1: Device summary

Order code	Temp. range	Package	Packing
ST3485ECDR	0 to 70 °C		
ST3485EBDR	-40 to 85 °C		2500 porto por roal
ST3485EIDT	40 to 405 %C	SO8 (tape and reel)	2500 parts per reel
ST3485EIYDT	-40 to 125 °C		

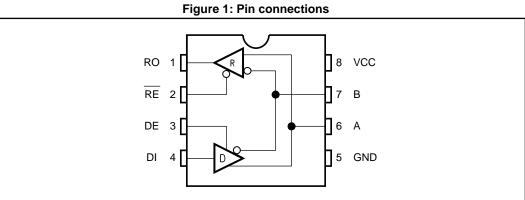
This is information on a product in full production.

## Contents

1	Pin con	ifiguration	3
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# 1 Pin configuration



	T	Table 2: Pin description
Pin n°	Symbol	Name and function
1	RO	Receiver output. If A > B by 200 mV, RO will be high; if A < B by 200 mV, RO will be low.
2	RE	Receiver output enable. RO is enabled when $\overline{RE}$ is low; RO is high impedance when $\overline{RE}$ is high. If $\overline{RE}$ is high and DE is low, the device will enter a low power shutdown mode.
3	DE	Driver output enable. The driver outputs are enabled by bringing DE high. They are high impedance when DE is low. If RE is high DE is low, the device will enter a low-power shutdown mode. If the driver outputs are enabled, the part functions as line driver, while they are high impedance, it functions as line receivers if RE is low.
4	DI	Driver input. A low on DI forces output A low and output B high. Similarly, a high on DI forces output A high and output B low.
5	GND	Ground.
6	А	Non-inverting receiver input and non-inverting driver output.
7	В	Inverting receiver input and inverting driver output.
8	VCC	Supply voltage: $V_{CC} = 3 V$ to 3.6 V.



## 2 Truth tables

Table 3: Truth table (driver)								
	Inputs		Out	puts				
RE	DE	DI	В	А	Mode			
x	Ц	Н	L	Н				
^	H	L	н	L	Normal			
L		х	7	7				
Н	L	X	Z	Z	Shutdown			

*Note:* X = "don't care"; Z = high impedance

#### Table 4: Truth table (receiver)

	Inputs		Output	
RE	DE	A-B	RO	Mode
	L	≥ 0.2 V	Н	
L		≤ -0.2 V	L	Normal
		Inputs open	Н	
Н		Х	Z	Shutdown

*Note:* X = "don't care"; Z = high impedance



## 3 Maximum ratings

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Symbol	Parameter	Value	Unit
Vcc	Supply voltage	7	
VI	Control input voltage ( RE , DE)	-0.3 to 7	
VDI	Driver input voltage (DI)	DE)       -0.3 to 7         -0.3 to 7         ±14         ±14         -0.3 to (Vcc + 0.3)         the line inputs         12         the logic         4         all other pins         2	V
Vdo	Driver output voltage (A, B)	±14	
V <sub>RI</sub>	Receiver input voltage (A, B)	±14	
Vro	Receiver output voltage (RO)	-0.3 to (Vcc + 0.3)	
	HBM: human body model for the line inputs (A and B) $^{(1)}$	12	
ESD	HBM: human body model for the logic inputs (DI, DE, $\overline{\text{RE}}$ ) <sup>(1)</sup>	4	kV
	Supply voltage7Control input voltage ( $\overline{RE}$ , DE)-0.3 to 7Driver input voltage (DI)-0.3 to 7Driver output voltage (A, B)±14Receiver input voltage (A, B)±14Receiver output voltage (A, B)±14Receiver output voltage (RO)-0.3 to (Vcc + 0.3)HBM: human body model for the line inputs (A and B) (1)12HBM: human body model for the logic nputs (DI, DE, $\overline{RE}$ ) (1)4		
	CDM: charged device model <sup>(2)</sup>	1.5	

#### Table 5: Absolute maximum ratings

#### Notes:

 $^{(1)}$ Human body model: 100 pF discharged through a 1.5 k $\Omega$  resistor between two pins of the device, done for all couples of pin combinations with other pins floating.

<sup>(2)</sup>Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to ground.



# 4 Electrical characteristics

Table 6: Electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

otherwise specifical rypical values are referred to TA = 20 - 07								
Symbol	Parameter	Test condition	าร	Min.	Тур.	Max.	Unit	
ISUPPLY	V <sub>CC</sub> power supply current	No load, DI = 0 V or V <sub>CC</sub>	$\frac{DE=V_{CC}}{RE}=0\;V$ or $V_{CC}$		1.3	2.2	mA	
001121			$\frac{DE=0\;V,}{RE}=0\;V$	_	1.2	1.9		
ISHDN	Shutdown supply current	$DE = 0 V$ , $\overline{RE} = V_{CC}$ , $DI = 0 V$ or $V_{CC}$			0.002	1	μA	

# Table 7: Logic input electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit	
VIL	Input logic threshold low	DE, DI, RE			1.3	0.8	V	
V <sub>IH</sub>	Input logic threshold high	DE, DI, RE					V	
l <sub>in1</sub>	Logic input current	DE, DI, RE				±2.0	μA	
h	Input ourrent (A_B)		V <sub>IN</sub> = 12 V			1	mA	
I <sub>IN2</sub>	Input current (A, B)	$DE = 0 V, V_{CC} = 0 \text{ or } 3.6 V$ $V_{IN} = -7 V$				-0.8	ΠA	



Electrical characteristics

Table 8: Transmitter electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
		R <sub>L</sub> = 100 Ω (RS-422) ( <i>Figure 2</i> )	2			
V <sub>OD</sub>	Differential drive output	R <sub>L</sub> = 54 Ω (RS-485) ( <i>Figure 2</i> )	1.5			
		R <sub>L</sub> = 60 Ω (RS-485) ( <i>Figure 3</i> )	1.5			
ΔVod	Change in magnitude of driver differential output voltage for complementary output states <sup>(1)</sup>	RL= 54 Ω or 100 Ω ( <i>Figure 2</i> )			0.2	V
Voc	Driver common mode output voltage	R <sub>L</sub> = 54 Ω or 100 Ω ( <i>Figure 2</i> )			3	
ΔVoc	Change in magnitude of driver common mode output voltage <sup>(1)</sup>	RL= 54 Ω or 100 Ω ( <i>Figure 2</i> )			0.2	
I <sub>OSD</sub>	Driver short-circuit output current				±250	mA

#### Notes:

 $^{(1)}\Delta V_{OD}$  and  $\Delta V_{OC}$  are the changes in  $V_{OD}$  and  $V_{OC}$ , respectively, when the DI input changes state.

Table 9: Receiver electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for
ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and
ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Vтн	Receiver differential threshold voltage	$V_{CM} = -7 V$ to 12 V, DE = 0	-0.2		0.2	V
$\Delta V$ th	Receiver input hysteresis	V <sub>CM</sub> = 0 V		70		mV
Vон	Receiver output high voltage	Iout = -4 mA, V <sub>ID</sub> = 200 mV ( <i>Figure 4</i> )	2			V
Vol	Receiver output low voltage	I <sub>OUT</sub> = 4 mA, V <sub>ID</sub> = -200 mV ( <i>Figure 4</i> )			0.4	v
I <sub>OZR</sub>	3-state (high impedance) output current at receiver	$V_{CC}$ = 3.6 V, $V_{O}$ = 0 V to $V_{CC}$			±1	μA
R <sub>RIN</sub>	Receiver input resistance	$V_{CM} = -7 V$ to 12 V	24			kΩ
Iosr	Receiver short-circuit current	V <sub>RO</sub> = 0 V to V <sub>CC</sub>	7		60	mA

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**Electrical characteristics** 

#### ST3485EB, ST3485EC, ST3485EI, ST3485EIY

Table 10: Driver switching characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
DR	Maximum data rate		12	15		Mbps
t <sub>DD</sub>	Differential output delay	R <sub>L</sub> = 60 Ω, C <sub>L</sub> = 15 pF ( <i>Figure 5</i> and <i>Figure 6</i> )		18	30	
t⊤D	Differential output transition time	R <sub>L</sub> = 60 Ω, C <sub>L</sub> = 15 pF ( <i>Figure 5</i> and <i>Figure 6</i> )		12	20	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay	R <sub>L</sub> = 27 Ω, C <sub>L</sub> = 15 pF ( <i>Figure 9</i> and <i>Figure 10</i> )		18	30	
tpds	t <sub>PLH</sub> - t <sub>PHL</sub>   driver propagation delay skew (1)	R <sub>L</sub> = 27 Ω, C <sub>L</sub> = 15 pF ( <i>Figure 9</i> and <i>Figure 10</i> )		2	5	
t <sub>PZL</sub>	Output enable time	$R_L$ = 110 $\Omega$ ( <i>Figure 11</i> and <i>Figure 12</i> )		19	35	ns
tрzн	Output enable time	R <sub>L</sub> = 110 Ω ( <i>Figure</i> 7 and <i>Figure 8</i> )		30	50	
t <sub>PHZ</sub>	Output disable time	R <sub>L</sub> = 110 Ω ( <i>Figure</i> 7 and <i>Figure 8</i> )		19	35	
t <sub>PLZ</sub>	Output disable time	$R_L$ = 110 $\Omega$ ( <i>Figure 11</i> and <i>Figure 12</i> )		30	50	
tskew	Differential output delay skew			1	3	
t <sub>PSH</sub>	Driver enable from shutdown to output high	R <sub>L</sub> = 110 Ω ( <i>Figure</i> 7 and <i>Figure</i> 8)		30	50	
tpsl	Driver enable from shutdown to output low	$R_L$ = 110 Ω ( <i>Figure 11</i> and <i>Figure 12</i> )		19	35	

#### Notes:

 $^{(1)}\mbox{Measured on } |\mbox{tplh}(A)\mbox{-tphL}(A)| \mbox{ and } |\mbox{tplh}(B)\mbox{-tphL}(B)|.$ 

Electrical characteristics

Table 11: Receiver switching characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
trplh, trphl	Propagation delay	$V_{ID} = 0 V$ to 3 V, $C_L = 15 \text{ pF}$ ( <i>Figure 13</i> and <i>Figure 14</i> )		30	50	
t <sub>RPDS</sub>	t <sub>RPLH</sub> - t <sub>RPHL</sub>   receiver propagation delay skew	$V_{ID} = 0 V$ to 3 V, $C_L = 15 \text{ pF}$ ( <i>Figure 13</i> and <i>Figure 14</i> )		1	3	
tprzl	Receiver output enable time to low level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 17)$		10	20	
tprzн	Receiver output enable time to high level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 16)$		10	20	ns
t <sub>PRHZ</sub>	Receiver output disable time from high level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 18)$	_	10	20	
t <sub>PRLZ</sub>	Receiver output disable time from low level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 19)$		10	20	
tprsh	Receiver output enable time from shutdown to high level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 16)$		10	20	
<b>t</b> PRSL	Receiver output enable time from shutdown to low level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 17)$		20	40	μs

#### Notes:

1.  $\Delta V_{OD}$  and  $\Delta V_{OC}$  are the changes in  $V_{OD}$  and  $V_{OC},$  respectively, when the DI input changes state.

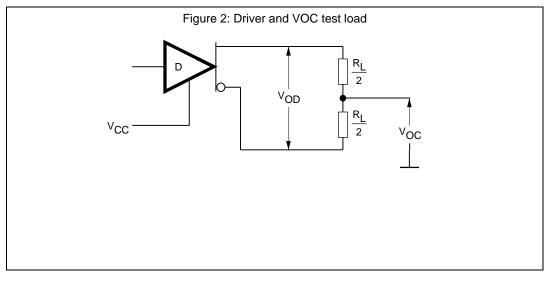
2. Measured on  $|t_{PLH}(A) - t_{PHL}(A)|$  and  $|t_{PLH}(B) - t_{PHL}(B)|$ .

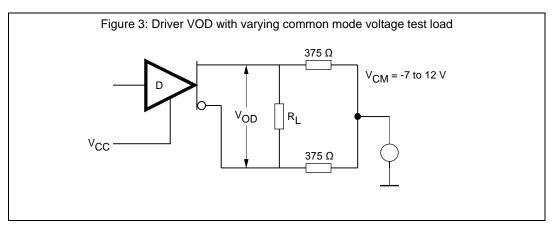
3. The transceivers are put into shutdown by bring RE high and DE low. If the input are

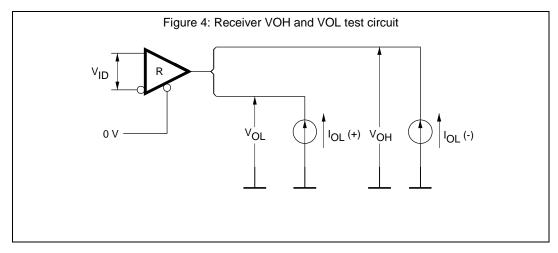
in state for less than 80 ns, the part are guaranteed not to enter shutdown. If the inputs are in this state for at least 300 ns, the parts are guaranteed to have entered shutdown.



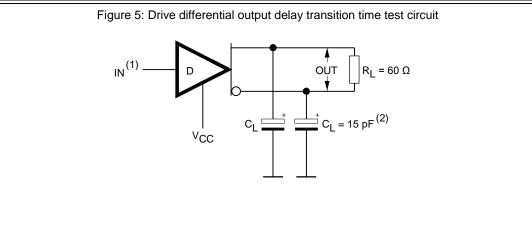
# 5 Test circuits and typical characteristics



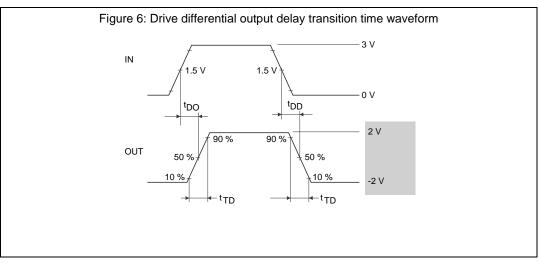


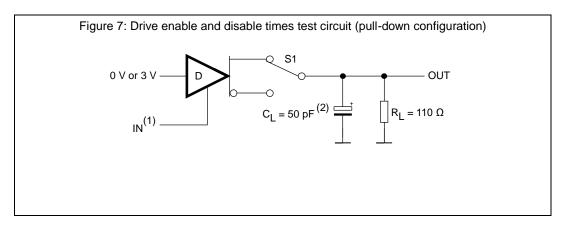






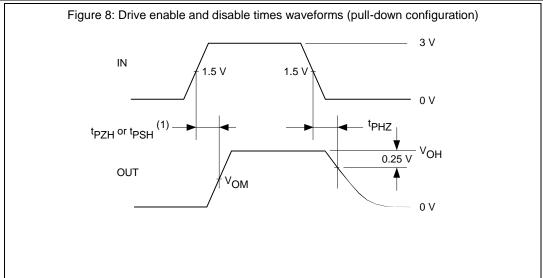
- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr  $\leq 6.0 \text{ ns}$ , Z<sub>0</sub> = 50  $\Omega$ .
- 2.  $C_L$  includes probe and stray capacitance



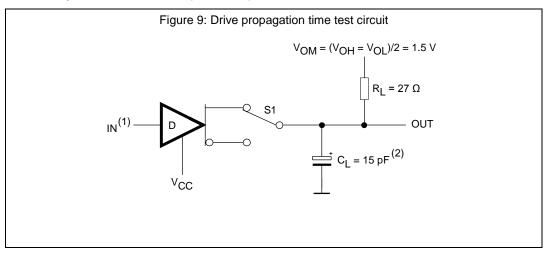


- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr  $\leq 6.0 \text{ ns}$ .
- 2.  $C_{L}$  includes probe and stray capacitance



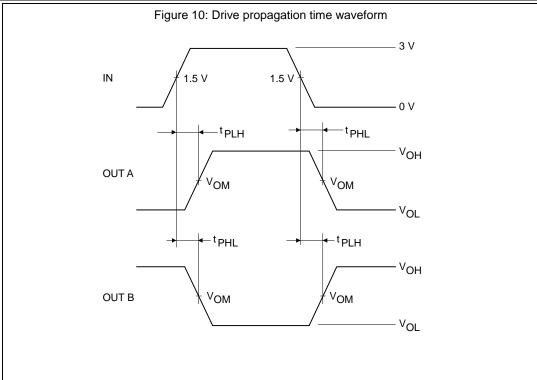


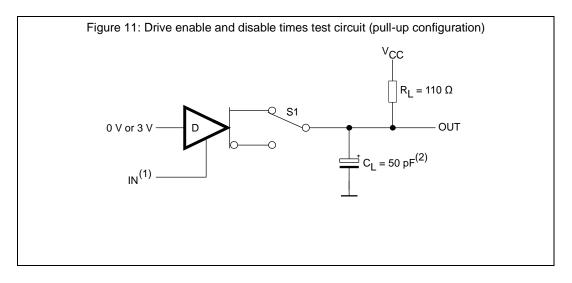
1. t<sub>PZH</sub> is valid if the driver is initially disabled ( RE is high), t<sub>PSH</sub> is valid if the driver is initially in shutdown mode (RE is low).



- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr  $\leq 6.0 \text{ ns}$ .
- 2.  $C_L$  includes probe and stray capacitance

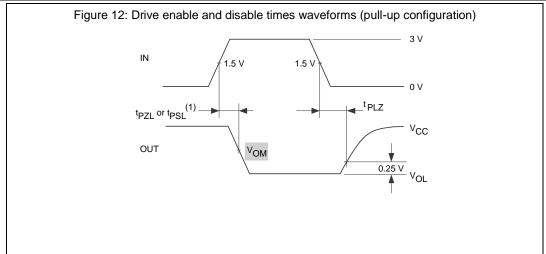




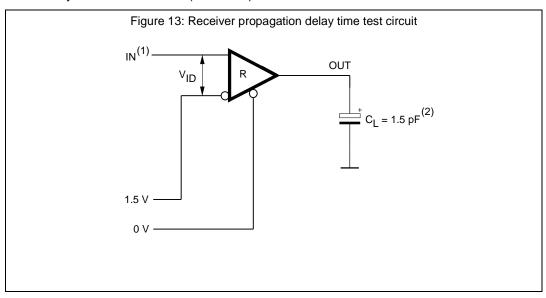


- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr  $\leq 6.0 \text{ ns}$ .
- 2.  $C_L$  includes probe and stray capacitance

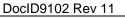




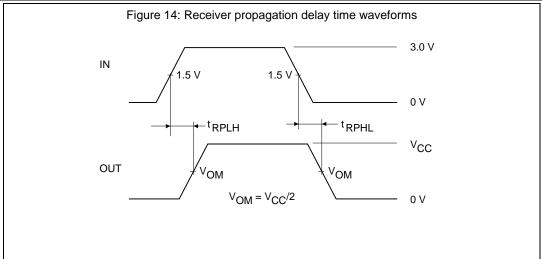
1. t<sub>PZL</sub> is valid if the driver is initially disabled ( RE is high), t<sub>PSL</sub> is valid if the driver is initially in shutdown mode (RE is low).

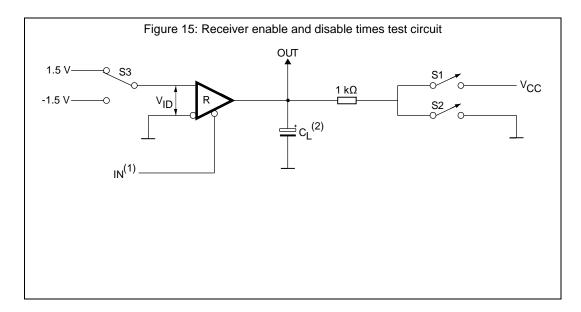


- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr  $\leq 6.0 \text{ ns}$ .
- 2.  $C_L$  includes probe and stray capacitance





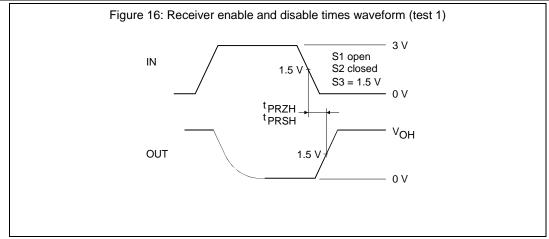


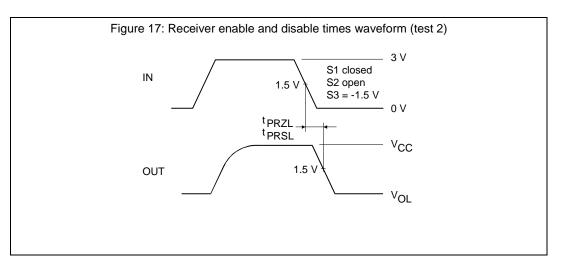


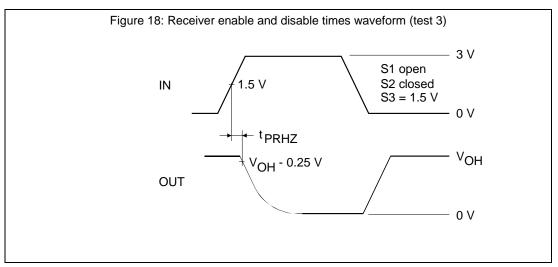
- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr  $\leq 6.0 \text{ ns}$ .
- 2.  $C_L$  includes probe and stray capacitance



#### Test circuits and typical characteristics

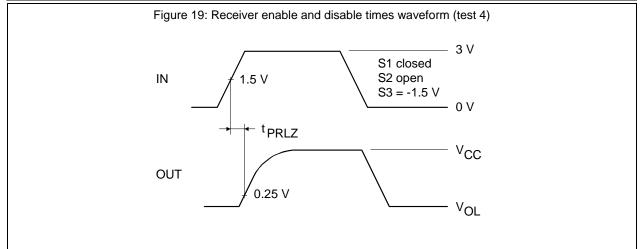


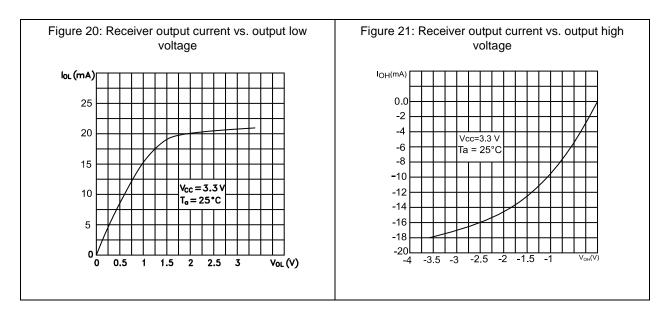


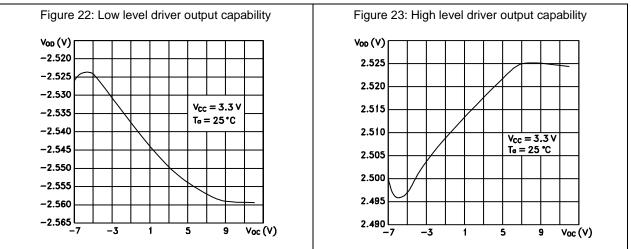




Test circuits and typical characteristics





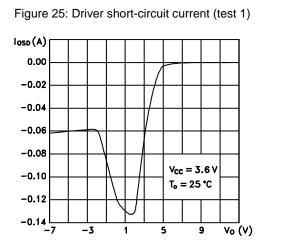


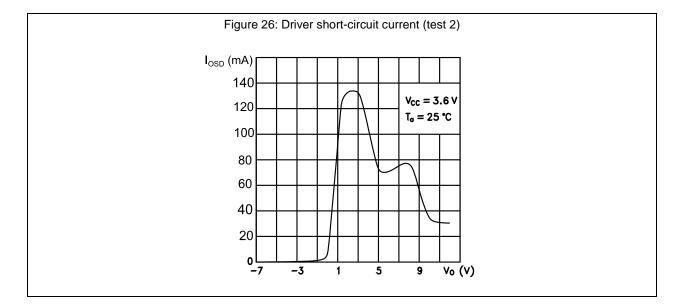
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#### Test circuits and typical characteristics

#### Figure 24: Receiver input characteristics I<sub>RI</sub> (mA) losd (A) 0.3 0.00 -0.02 0.2 -0.04 0.1 -0.06 0 -0.08 $\begin{array}{l} V_{CC}=0 \ V \\ T_{\sigma}=25 \ ^{\circ}\!C \end{array}$ -0.10 -0.1 -0.12 -0.2 -3 5 9 $V_{RI}(V)$ -7 1







## 6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

## 6.1 SO8 package information

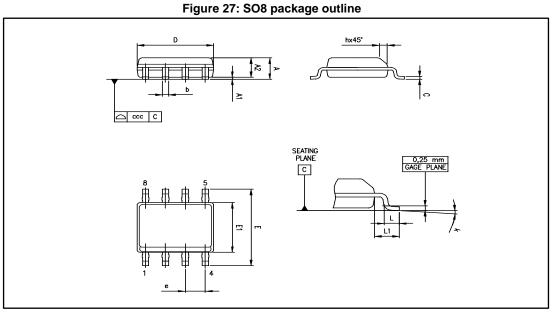


Table 12: SO8 mechanical data	Table 1	2:	<b>SO</b> 8	mechanical	data
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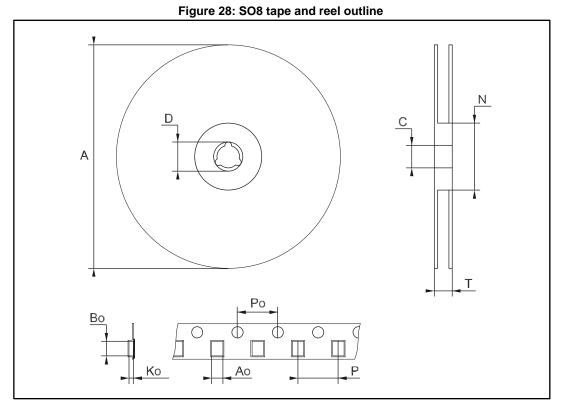
	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max	
Α			1.75			0.069	
A1	0.10		0.25	0.004		0.010	
A2	1.25			0.049			
b	0.28		0.48	0.011		0.019	
С	0.17		0.23	0.007		0.010	
D	4.80	4.90	5.00	0.189	0.193	0.197	
E	5.80	6.00	6.20	0.228	0.236	0.244	
E1	3.80	3.90	4.00	0.150	0.154	0.157	
е		1.27			0.050		
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
L1		1.04			0.040		
k	0°		8°	0°		8°	
CCC			0.10			0.004	



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## 6.2 SO8 tape and reel information



1. Drawing not to scale

#### Table 13: SO8 tape and reel mechanical data

	Dimensions					
Symbol	mm			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



# 7 Ordering information

Order code	Temperature range	Package	Packaging	Marking
ST3485ECDR	0 to 70 °C			3485EC
ST3485EBDR	-40 to 85 °C	500	Topo and roal	3485EB
ST3485EIDT	-40 to 125 °C	SO8	Tape and reel	3485EI
ST3485EIYDT <sup>(1)</sup>	-40 to 125 °C (automotive grade)			3485EIY

#### Table 14: Order codes

#### Notes:

<sup>(1)</sup>Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q 002 or equivalent.



#### **Revision history** 8

Table 15: Document	revision	history
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Date	Revision	Changes		
20-Jun-2005	2	Mistake on table 12 t <sub>ZL(SHDN)</sub> ms ==> µs.		
30-Aug-2005	3	Remove (TRUE) on title, description has been updated in cover page. The $V_{TH}$ and $DV_{TH}$ values are changed in table 10.		
07-Apr-2006	4	Order codes updated.		
12-Nov-2007	5	Added Table 1.		
18-Dec-2013	6	Updated Features (added SO-8 package, replaced human body model by ±15 kV IEC 61000-4-2 air discharge and IEC 1000-4-2 by IEC 61000-4-2). Updated Description (renamed device to ST3485EB/EC, replaced human body model by ±15 kV IEC 61000-4-2 air discharge). Removed ST3485ECN device from Table 1. Updated title of Table 6, cross-references, replaced human body model (HBM) by ±15 kV IEC 61000-4-2 air discharge and IEC 1000-4-2 by IEC 61000-4-2. Added notes below Table 9. Updated Table 10 to Table 12 (updated data, cross-references). Updated Figure 5 to Figure 16 (updated data, added notes below figures and highlighted some parts of Figure 6 and Figure 12). Removed DIP-8 package from Section 6: "Package information" and whole document. Reformatted Section 6: "Package information" (added Figure 27, Figure 28, Table 13 and Table 14, reversed order of figures and table). Minor corrections throughout document.		
12-Jun-2015 7		Added part number ST3485EIY Added order code ST3485EIYDT and pointed out in Features it is automotive grade. Table 7 and Table 9 through to Table 12: replaced $T_A = -40$ to 85 °C with $T_A$ = 0 to 70 °C (ST3485ECDR), $T_A = -40$ to 85 °C (ST3485EBDR), and $T_A = -40$ to 125 °C (ST3485EIYDT). Updated titles of figures 7, 8, 11, 12, 16, 17, 18, 19, 25, and 26		
15-Mar-2016	8	Table 5: added ESD information Removed "Table 6: ESD performance: transmitter outputs, receiver inputs (A, B)". Added Section 7: "Ordering information"		
02-Aug-2016	Added new part number ST3485EI Table 1: "Device summary": added information for new part number ST3485EI. Removed " <i>Note</i> " icons throughout datasheet 9 Section 4: "Electrical characteristics": updated TA information Section 5: "Test circuits and typical characteristics": removed overline bar concerning "RE is low" in note 1 of figures 8 and 12. Table 14: "Order codes": added ST3485EIDT and updated footnote 1 (ST3485EIYDT now qualified).			
25-Aug-2016	10	Table 14: "Order codes": updated order codes ST3485EBDR and ST3485ECDR.		

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85EB, ST3485EC, ST3485EI, ST3485EIY Revision histo			
Date	Revision	Changes	
26-Oct-2017	11	Updated Figure 20: "Receiver output current vs. output low voltage", Figure 21: "Receiver output current vs. output high voltage", Figure 24: "Receiver input characteristics" and Figure 26: "Driver short-circuit current (test 2)".	



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